

Inchange Semiconductor

Product Specification

Silicon NPN Power Transistors

2SC4742

DESCRIPTION

- With TO-3PN package
- Built-in damper diode
- High breakdown voltage

APPLICATIONS

- Character display horizontal deflection output applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

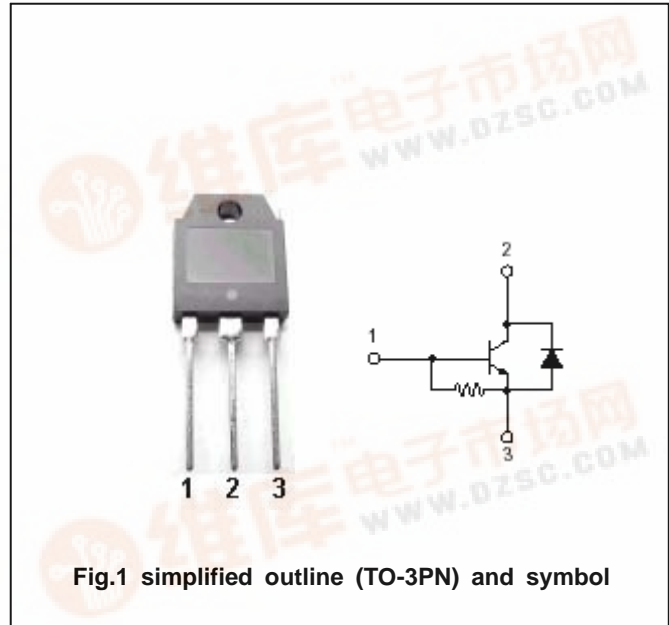


Fig.1 simplified outline (TO-3PN) and symbol

Absolute maximum ratings(Ta= )

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>CEO</sub>	Collector-emitter voltage	Open base	1500	V
V <sub>EBO</sub>	Emitter-base voltage	Open collector	6	V
I <sub>C</sub>	Collector current		6	A
I <sub>CM</sub>	Collector current-peak		7	A
I <sub>C(surge)</sub>	Collector current-surge		16	A
I <sub>o</sub>	C to E diode forward current		7	A
P <sub>C</sub>	Collector power dissipation	T <sub>C</sub> =25	50	W
T <sub>j</sub>	Junction temperature		150	
T <sub>stg</sub>	Storage temperature		-55~150	

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## CHARACTERISTICS

T<sub>j</sub>=25 unless otherwise specified

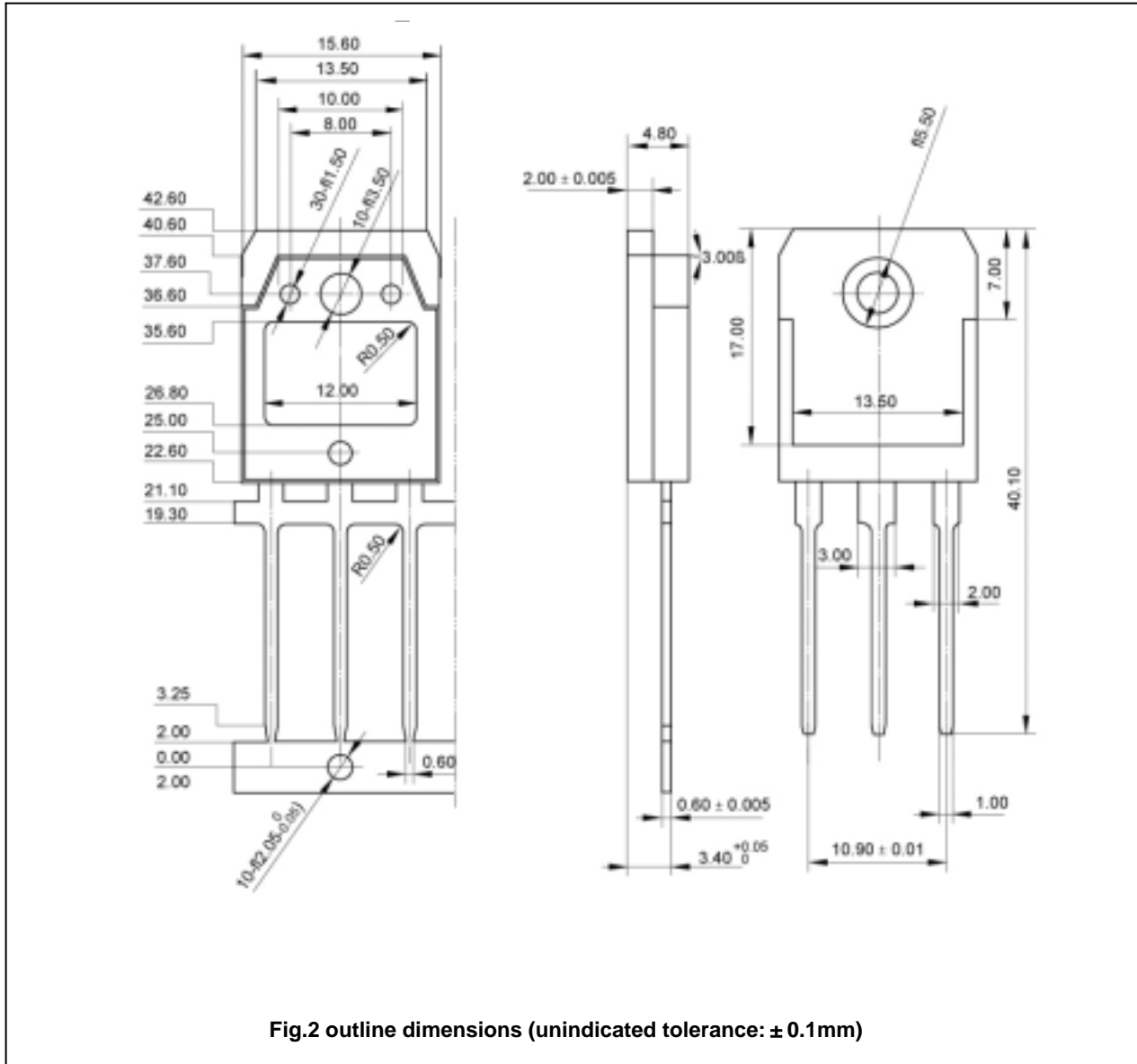
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =400mA ; I <sub>C</sub> =0	6			V
I <sub>CES</sub>	Collector cut-off current	V <sub>CE</sub> =1500V; R <sub>BE</sub> =0			0.5	mA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =1A ; V <sub>CE</sub> =5V			25	
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =5A ; I <sub>B</sub> =1.25A			2.0	V
V <sub>BE(sat)</sub>	Base-emitter saturation voltage	I <sub>C</sub> =5A ; I <sub>B</sub> =1.25A			1.5	V
V <sub>ECF</sub>	Diode forward voltage	I <sub>F</sub> =6A			2.0	V
t <sub>f</sub>	Fall time	I <sub>CP</sub> =5A; I <sub>B1</sub> =1A; I <sub>B2</sub> =-2A			0.4	μs

固电半导体  
INCHANGE SEMICONDUCTOR

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PACKAGE OUTLINE



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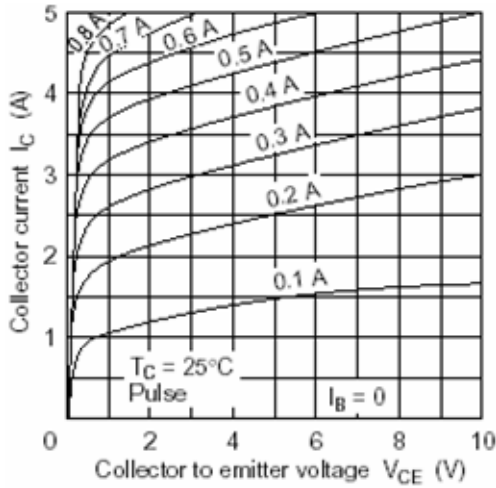


Fig.3 Static Characteristic

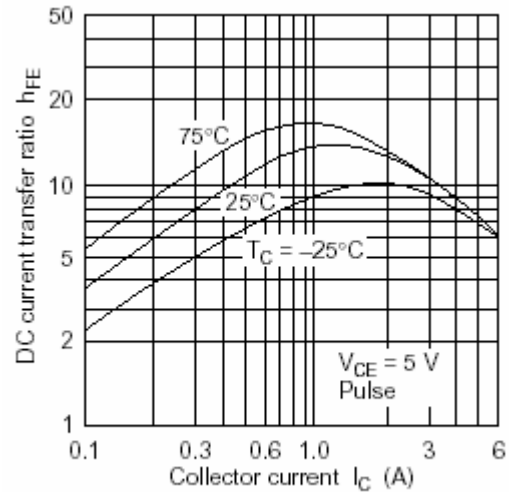


Fig.4 DC current Gain

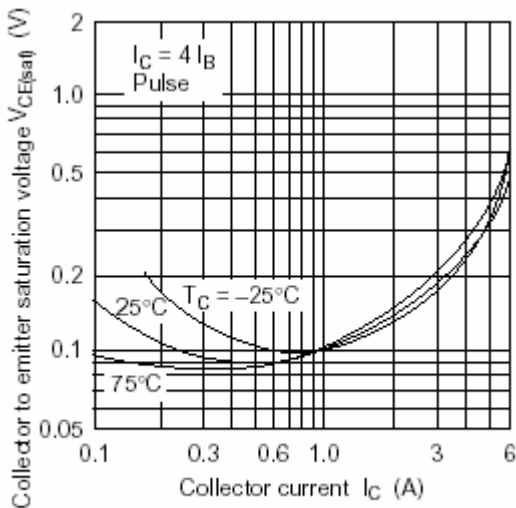


Fig.5 Collector-Emitter Saturation Voltage

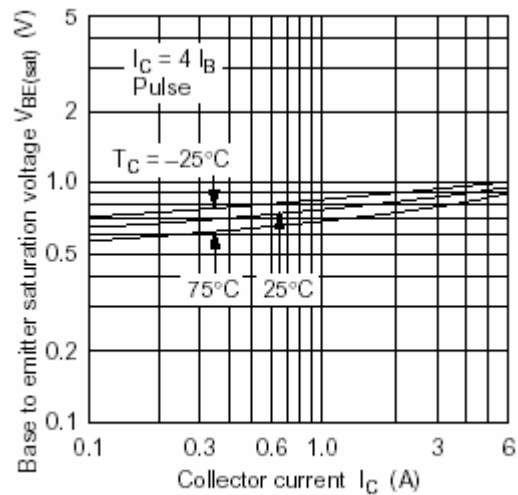


Fig.6 Base-Emitter Saturation Voltage

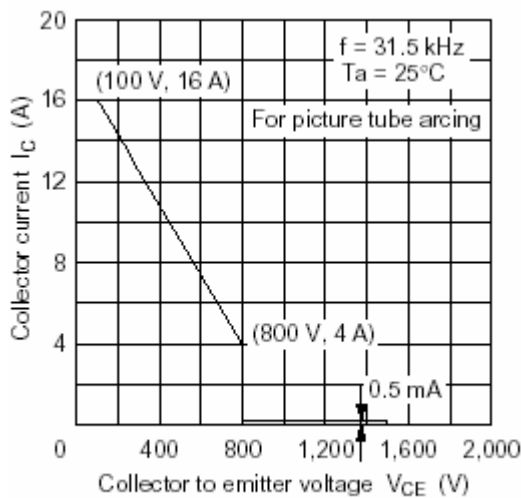


Fig.7 Safe Operating Area